## NSN 5961-00-995-1674

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-995-1674 **Inclosure Material:** Metal **Overall Length:** 0.400 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakover voltage, dc **Current Rating Per Characteristic:** 60.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npnp **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

A110a0